

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	66	(light adj emitting adj diode) and clad and (second adj conductivit\$5 adj type)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/04/16 14:10
2	BRS	L2	62	1 and @ay<2000	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/04/16 12:52
3	BRS	L3	1	2 and (delta adj doping) and (quantum adj well)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/04/16 14:09
4	BRS	L4	9	(light adj emitting adj diode) and (quantum adj well) and (delta adj doping)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/04/16 14:15
5	BRS	L5	10	(light adj emitting adj diode) and (quantum adj well) and (delta adj dop\$4) and (barrier well)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/04/16 14:21

	Type	L #	Hits	Search Text	DBs	Time Stamp
6	BRS	L6	0	(light adj emitting adj diode) and (delta adj dop\$3 adj (well barrier))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/04/16 14:23

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	66	(light adj emitting adj diode) and clad and (second adj conductivit\$5 adj type)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/04/16 12:52
2	BRS	L2	62	1 and @ay<2000	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2002/04/16 12:52